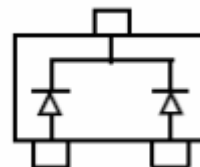


FEATURES

Extremely Fast Switching Speed



Maximum Ratings @T_A=25°C

Parameter	Symbol	Limits	Unit
Peak Repetitive Peak reverse voltage	V _{RRM}	30	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
Forward Continuous Current	I _{FM}	200	mA
Power Dissipation	P _D	200	mW
Storage temperature	T _{STG}	-55-150	°C

Electrical Characteristics @T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V _{(BR)R}	30			V	I _R =100μA
Forward voltage	V _{F1}			0.24	V	I _F =0.1mA
	V _{F2}			0.32	V	I _F =1mA
	V _{F3}			0.40	V	I _F =10mA
	V _{F4}			0.50	V	I _F =30mA
	V _{F5}			1	V	I _F =100mA
Reverse current	I _R			2	μA	V _R =25V
Diode Capacitance	C _D			10	pF	V _R =1V, f=1MHz
Reverse Recovery Time	t _{rr}			5	nS	I _F =I _R =10mA I _{rr} =0.1I _R , R _L =100Ω

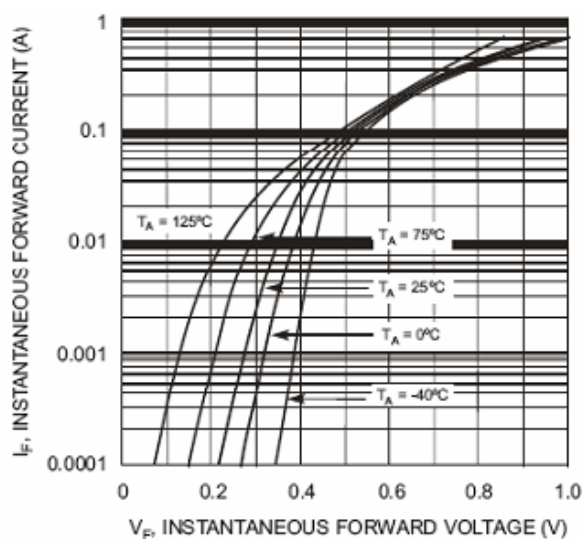


Fig. 1 Forward Characteristics

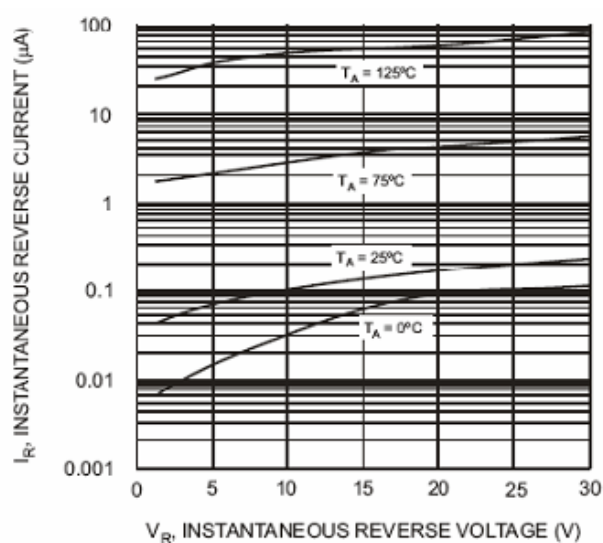


Fig. 2 Typical Reverse Characteristics

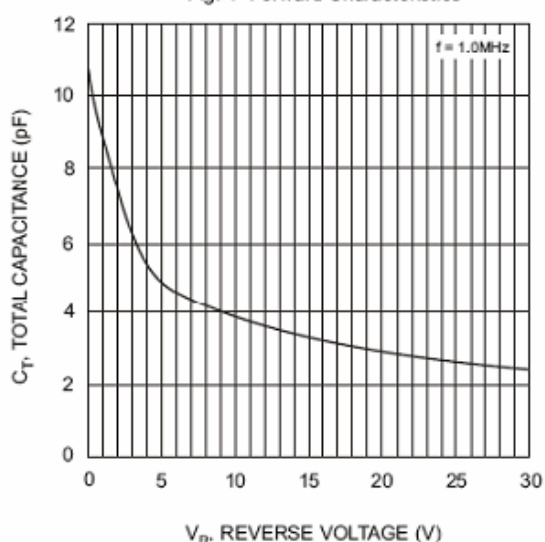


Fig. 3 Typical Capacitance vs. Reverse Voltage

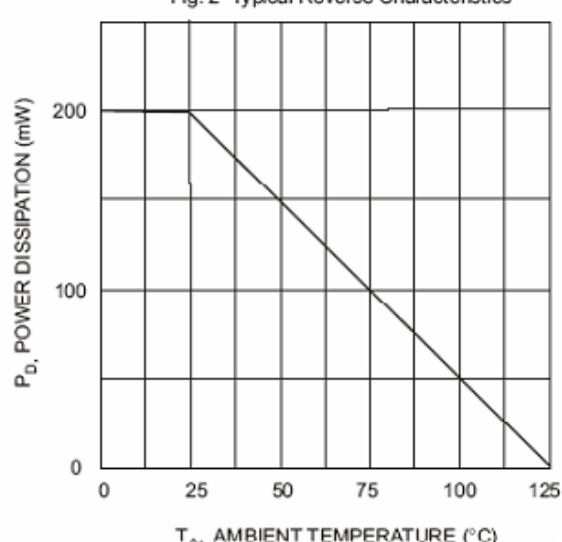
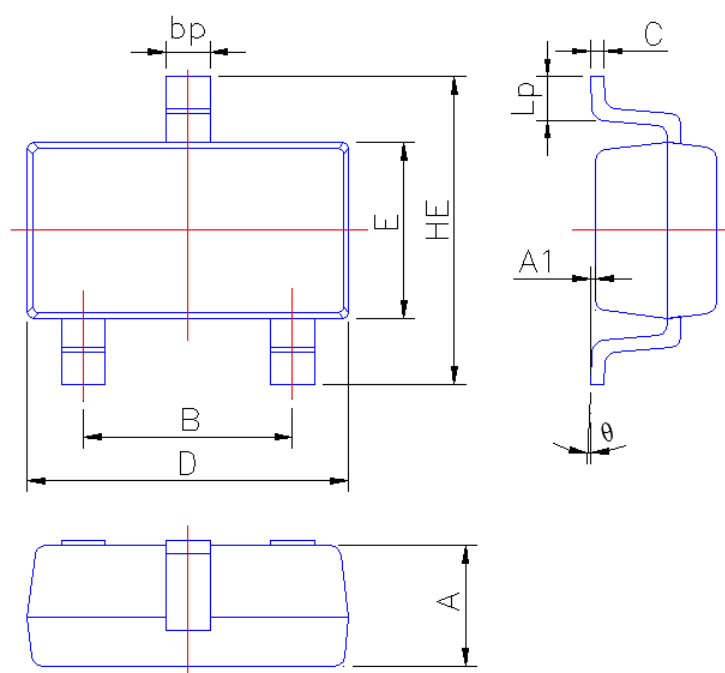


Fig. 4 Power Derating Curve

SOT-23-3L-Package Outline Dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	1.05	1.20
A1	0.010	0.100
B	1.80	2.00
bp	0.35	0.50
C	0.09	0.15
D	2.80	3.00
E	1.50	1.70
HE	2.60	3.00
Lp	0.25	0.55
θ	2°	6°